

December 2013

## FDPF320N06L N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET 60 V, 21 A, 25 mΩ

## Features

- +  $R_{DS(on)}$  = 20 m $\Omega$  (Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 21 A
- $R_{DS(on)}$  = 23 m $\Omega$  (Typ.) @  $V_{GS}$  = 5 V,  $I_D$  = 17 A
- Low Gate Charge (Typ. 23.2 nC)
- Low C<sub>rss</sub> (Typ. 64 pF)
- Fast Switching Speed
- 100% Avalanche Tested
- · Improved dv/dt Capability
- RoHS Compliant

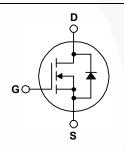
## Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

## Applications

- Consumer Appliances
- LCD/LED/PDP TV





## MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter			Unit	
V <sub>DSS</sub>	Drain to Source Voltage		60	V		
V <sub>GSS</sub>	Gate to Source Voltage		±20	V		
ID	Drain Current	- Continuous (T <sub>C</sub> = 25°C	C)	21	•	
	Drain Current	- Continuous (T <sub>C</sub> = 100 <sup>6</sup>	°C)	15	A	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	84	A	
E <sub>AS</sub>	Single Pulsed Avalanche	(Note 2)	66	mJ		
dv/dt	Peak Diode Recovery dv	(Note 3)	6.0	V/ns		
P <sub>D</sub>	Dower Dissinction	(T <sub>C</sub> = 25 <sup>o</sup> C)		26	W	
	Power Dissipation	- Derate Above 25°C		0.17	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +175	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

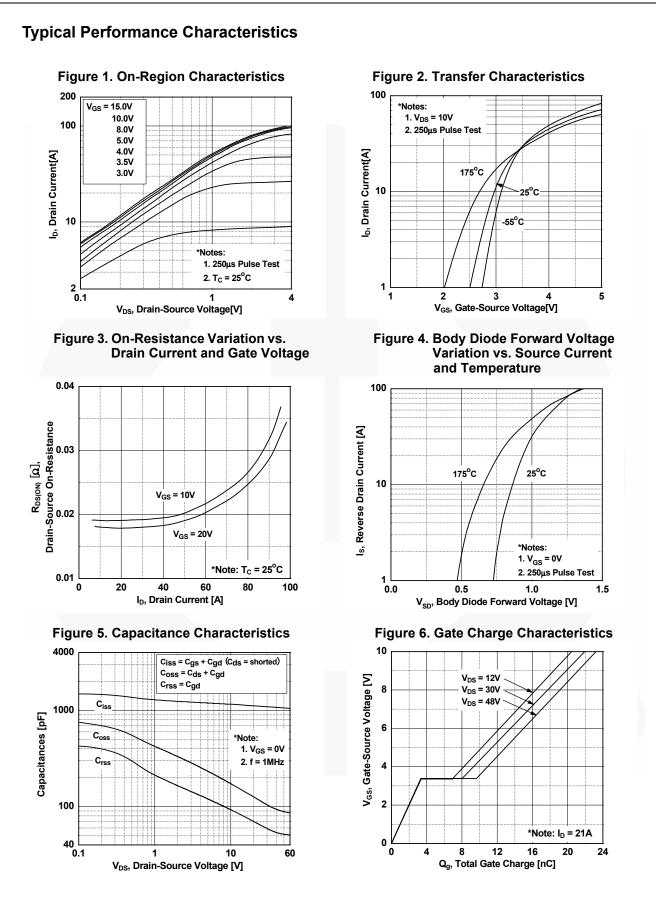
## **Thermal Characteristics**

Symbol	Parameter	FDPF320N06L	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	5.8	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	C/VV

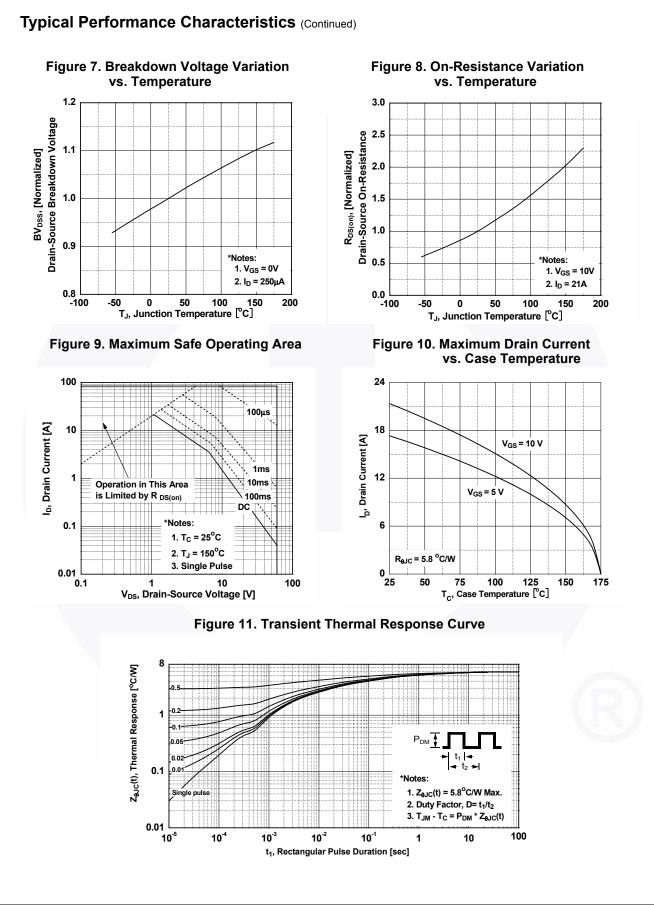
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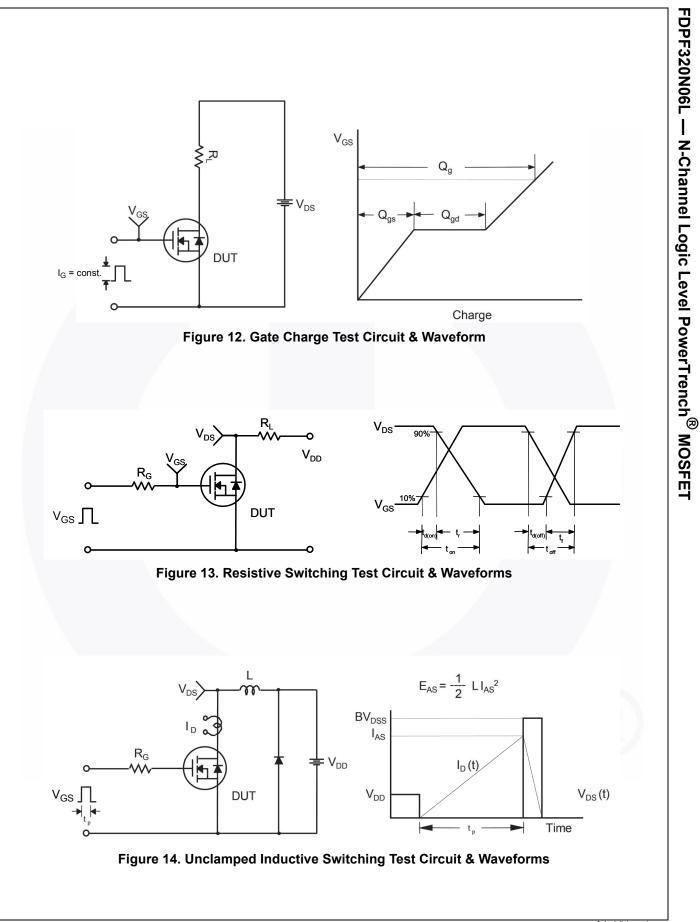
Part Number Top Mark Pa		Packa	kage Packing Method Reel Size			Tape Width		Quantity		
		TO-220	• •			N/A		50 units		
Electrica	l Char	acteristics T <sub>c</sub> = 2	5ºC unless	s otherv	vise noted.					
Symbol		Parameter		Test Conditions			Min.	Тур.	Max.	Unit
Off Charac	teristic	S								
BV <sub>DSS</sub>	Drain to	Source Breakdown Vol	tage	I <sub>D</sub> =	250 μΑ, V <sub>GS</sub> = 0 V		60	-	-	V
ΔBV <sub>DSS</sub> /ΔT,	Breakdown Voltage Temperature Coefficient		0	$I_D = 250 \ \mu$ A, Referenced to $25^{\circ}$ C			-	0.04	-	V/ºC
I <sub>DSS</sub>		Zero Gate Voltage Drain Current		$V_{DS} = 48 V, V_{GS} = 0 V$			-	-	1 500	μA
I <sub>GSS</sub>	Gate to	Body Leakage Current	_	-	= 48 V, T <sub>C</sub> = 150°0 = ±20 V, V <sub>DS</sub> = 0 \		-	-	±100	μA
				00	/ 03					
On Charac									1	
V <sub>GS(th)</sub>	Gate Th	nreshold Voltage			= V <sub>DS</sub> , I <sub>D</sub> = 250 μA	4	1.0	-	2.5	V
R <sub>DS(on)</sub>	Static D	rain to Source On Resis	tance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 21 A			-	20	25	mΩ
. ,	_			$V_{GS} = 5 V, I_D = 17 A$ $V_{DS} = 10 V, I_D = 21 A$			-	23	38	mΩ
9 <sub>FS</sub>	Forward	d Transconductance	_				-	34	-	S
Dynamic C	haracte	eristics								
C <sub>iss</sub>	Input Ca	apacitance		$V_{\rm DS} = 25 \text{ V}, \text{ V}_{\rm GS} = 0 \text{ V}$			-	1105	1470	pF
C <sub>oss</sub>	Output (	Capacitance				-	115	150	pF	
C <sub>rss</sub>	Reverse	everse Transfer Capacitance		f = 1 MHz		-	64	-	pF	
Q <sub>g(tot)</sub>		ate Charge at 10V		V <sub>GS</sub>	= 10 V		-	23.2	30.2	nC
Q <sub>g(tot)</sub>		ate Charge at 5V			= 5 V	_	-	12.7	16.5	nC
Q <sub>gs</sub>	Gate to	Source Gate Charge			= 48 V,	(Note 4)	-	3.4	-	nC
Q <sub>gd</sub>	Gate to	Gate to Drain "Miller" Charge		$I_D = 21 \text{ A}$		-	6.3	-	nC	
Switching	Charac	teristics								
t <sub>d(on)</sub>		Delay Time					-	16	42	ns
t <sub>r</sub>		n Rise Time		V <sub>DD</sub> = 30 V, I <sub>D</sub> = 21 A,				34	78	ns
t <sub>d(off)</sub>		f Delay Time		$V_{GS} = 5 V, R_G = 4.7 \Omega$		-	-	27	64	ns
-a(011) t <sub>f</sub>		f Fall Time				(Note 4)		8	26	ns
ESR		ent Series Resistance (C	G-S)	f = 1	f = 1MHz		-	2	-	Ω
	-1	de Characteristics							01	•
s	Maximum Continuous Drain to Source Diode Forward Current						-	-	21	A
SM		Maximum Pulsed Drain to Source Diode F					-	-	84	A V
V <sub>SD</sub>		Source Diode Forward	vollage	$V_{GS} = 0 V, I_{SD} = 21 A$ $V_{GS} = 0 V, I_{SD} = 21 A, V_{DD} = 48 V,$ $dI_{F}/dt = 100 A/\mu s$		( - 40.)(	-	- 27	1.3	
t <sub>rr</sub> Q <sub>rr</sub>		Recovery Charge				-	27	-	ns nC	
<b>lotes:</b> . Repetitive rating 2. L = 1 mH, I <sub>AS</sub> = 3. I <sub>SD</sub> ≤ 21 A, di/dt	11.5 A, R <sub>G</sub> = ≤ 200 A/µs, V	limited by maximum junction ter 25 $\Omega$ , starting T <sub>J</sub> = 25°C. $I_{DD} \le BV_{DSS}$ , starting T <sub>J</sub> = 25°C verating temperature typical char							Œ	2

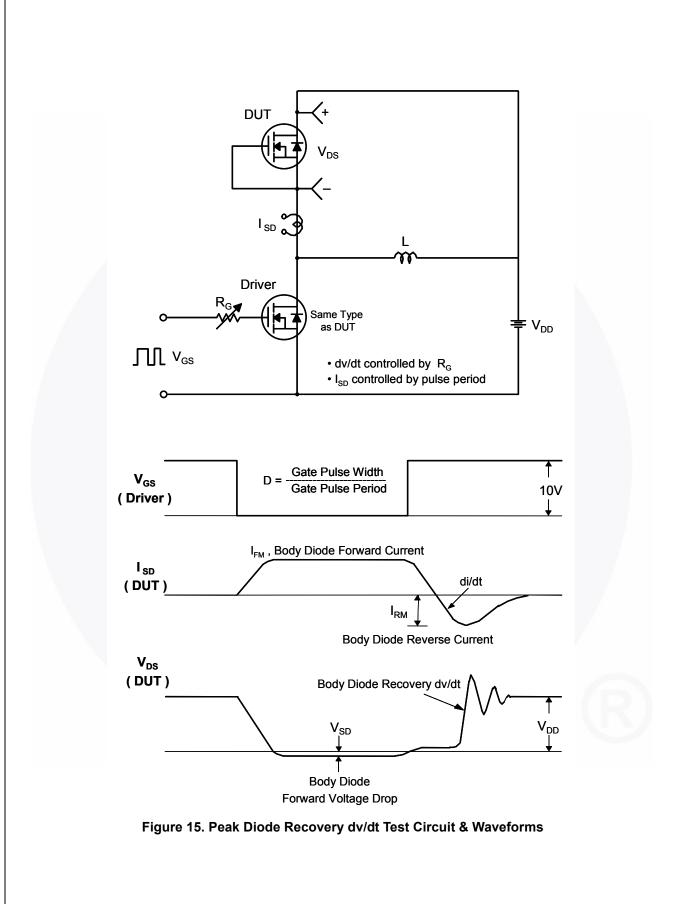
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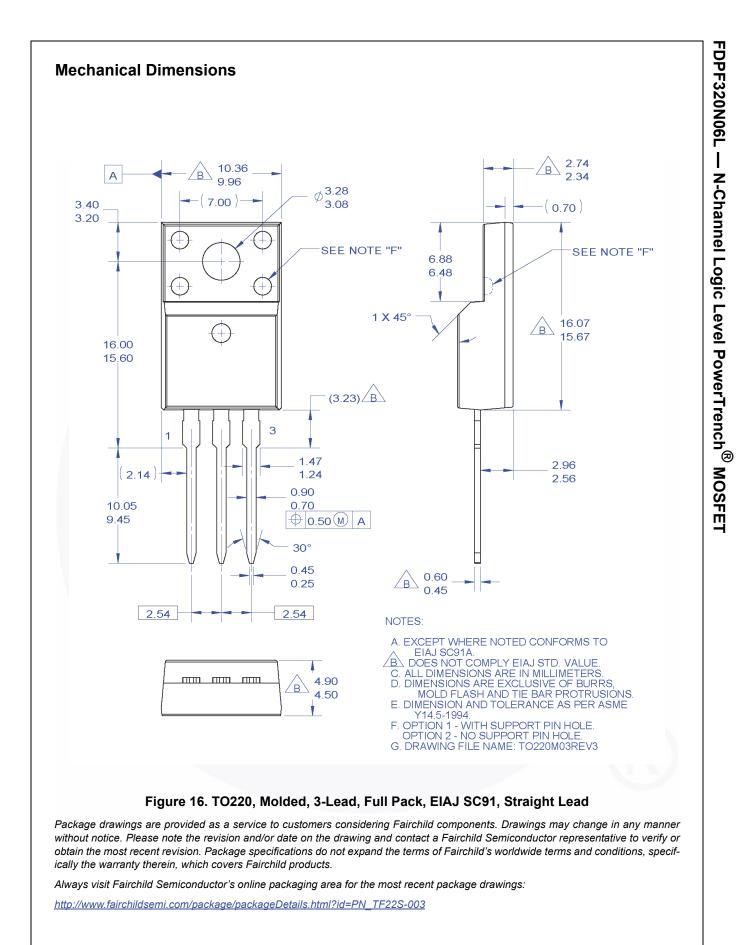
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